

1N5807US/1N5809US/1N5811US Superfast Recovery Diodes Surface Mount (US)

POWER DISCRETES

Description

Quick reference data

V_R 50 -150 V

 $I_{\rm F}$ 1N5807US to 1N5811US = 6A

 t_{rr} 1N5807US to 1N5811US = 30nS

 $I_{R}^{"}$ 1N5807US to 1N5811US = 5 μ A

Features

- ◆ Very low reverse recovery time
- ◆ Hermetically sealed non-cavity construction
- ◆ Soft, non-snap, off recovery characteristics
- Very low forward voltage drop

These products are qualified to MIL-PRF-19500/477 and are preferred parts as listed in MIL-HDBK-5961. They can be supplied fully released as JANTX , JANTXV and JANS versions.

Electrical Specifications

Electrical specifications @ $T_A = 25$ °C unless otherwise specified.

	Symbol	1N5807US	1N5809US	1N5811US	Units
Working Reverse Voltage	$V_{_{\mathrm{RWM}}}$	50	100	150	V
Repetitive Reverse Voltage	V_{RRM}	50	100	150	V
Average Forward Current (@ 75°C lead length = 0.375')	I _{F(AV)}	6.0		А	
Repetitive Surge Current (@ 55°C in free air lead length = 0.375')	I _{FRM}	25		А	
Non-Repetitive Surge Current (tp = 8.3mS @ Vr & T _{JMAX})	I _{FSM}	125		А	
Storage Temperature Range	T _{STG}	-65 to +175		°C	
Average Forward Current Max (pcb mounted: $T_A = 55^{\circ}C$) Sine wave Square wave (d = 0.5)	I _{F(AV)} I _{F(AV)}	1.7 1.8		A	
Pt for fusing (t = 8.3mS) max	l²t	32		A ² S	
Forward Voltage Drop max @ T _J = 25°C	V _F	0.875 @ 4A		V	
Reverse Current max @ V_{WRM} , $T_J = 25^{\circ}C$ @ V_{WRM} , $T_J = 100^{\circ}C$	l R I _R	5.0 150		μА	
Reverse Recovery Time max (1.0A I_F to 1.0A I_{RM} recover to 0.25A $I_{RM(REC)}$)	trr		30		nS
Junction Capacitance typ @ V _R = 5V f = 1MHz	C _J	60		pF	
Thermal Resistance to end cap	R _{eJEC}		6.5		°C/W



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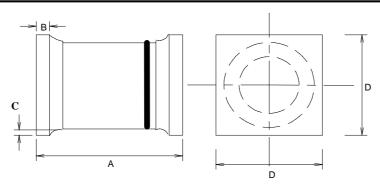
Ordering information				
Part Number	Description			
1N5807US, 1N5809US,	Surface Mount ⁽¹⁾			

Note:

(1) Available in trays and tape and reel packaging. Please consult factory for quantities.

Outline Drawing

1N5811US



*Cathode is denoted by a black band on a white body.

	Dimensions in Inches 1N5807US - 1N5811US				
	MIN	MAX			
Α	0.2	0.225			
В	0.019	0.028			
С	0.003	-			
D	0.137	0.148			

Contact Information

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